NPN Triple Diffused Planar Silicon Transistor



2SC4430

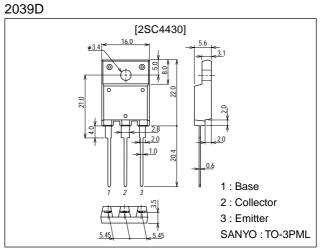
800V/12A Switching Regulator Applications

Features

- \cdot High breakdown voltage, high reliability.
- \cdot Fast switching speed (t_f : 0.1 \mu s typ).
- \cdot Wide ASO.
- · Adoption of MBIT process.
- · Micaless package facilitating easy mounting.

Package Dimensions

unit:mm



Specifications

Absolute Maximum Ratings at Ta = 25°C

Parameter	Symbol	Conditions	Ratings	Unit
Collector-to-Base Voltage	VCBO		1100	V
Collector-to-Emitter Voltage	VCEO		800	V
Emitter-to-Base Voltage	VEBO		7	V
Collector Current	۱ _C		12	A
Collector Current (Pulse)	ICP	PW≤300µs, duty cycle≤10%	30	A
Base Current	Ι _Β		6	A
Collector Dissipation	PC		3	W
		Tc=25°C	65	W
Junction Temperature	Tj		150	°C
Storage Temperature	Tstg		-55 to +150	°C

Electrical Characteristics at Ta = 25°C

Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	Offic
Collector Cutoff Current	ICBO	V _{CB} =800V, I _E =0			10	μΑ
Emitter Cutoff Current	IEBO	V _{EB} =5V, I _C =0			10	μΑ
DC Current Gain	hFE1*	V _{CE} =5V, I _C =0.8A	10		40	
	h _{FE} 2	$V_{CE}=5V, I_{C}=4A$	8			

*: The $h_{FE}l$ of the 2SC4430 is classified as follows. When specifying the $h_{FE}l$ rank, specify two ranks or more in principle.

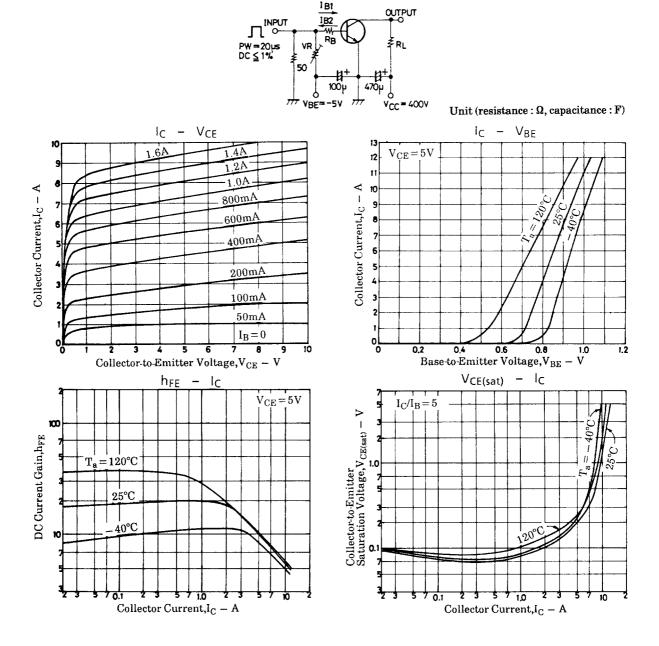
10 K 20 15 L 30 20 M 40

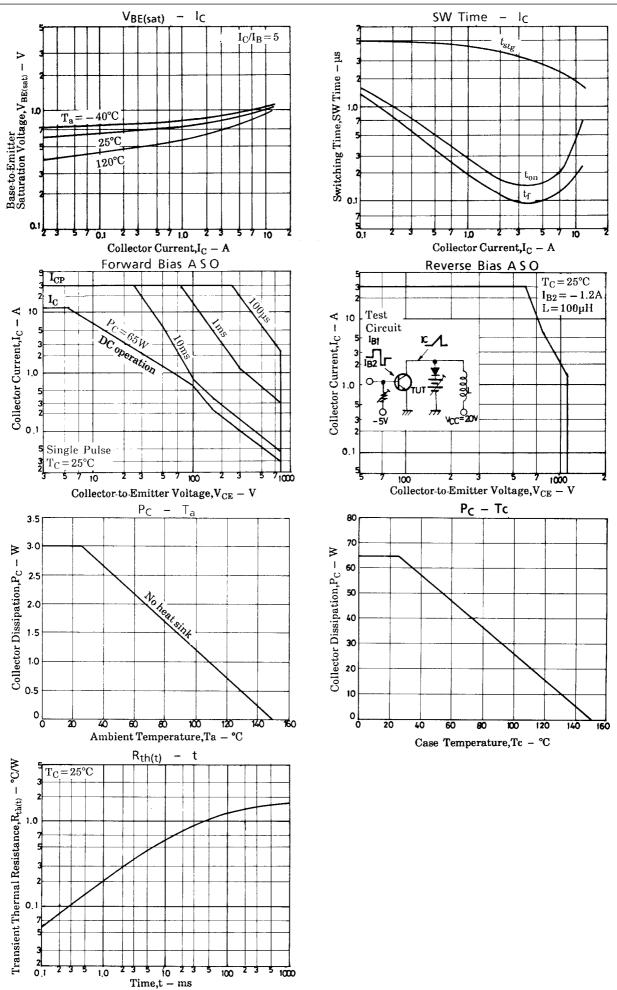
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Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	Unit
Collector-to-Emitter Saturation Voltage	V _{CE(sat)}	I _C =6A, I _B =1.2A			2.0	V
Base-to-Emitter Saturation Voltage	V _{BE(sat)}	I _C =6A, I _B =1.2A			1.5	V
Gain-Bandwidth Product	fT	V _{CE} =10V, I _C =0.8A		15		MHz
Output Capacitance	Cob	V _{CB} =10V, f=1MHz		215		pF
Collector-to-Base Breakdown Voltage	V(BR)CBO	I _C =1mA, I _E =0	1100			V
Collector-to-Emitter Breakdown Voltage	V(BR)CEO	I _C =5mA, R _{BE} =∞	800			V
Emitter-to-Base Breakdown Voltage	V _{(BR)EBO}	I _E =1mA, I _C =0	7			V
Collector-to-Emitter Sustain Voltage	V _{CEX(sus)}	I _C =6A, I _{B1} =1.2A, I _{B2} =-1.2A, L=500µH, Clamped	800			V
Turn-ON Time	ton	I _C =8A, I _{B1} =1.6A, I _{B2} =-3.2A, R _L =50Ω, V _{CC} =400V			0.5	μs
Storage Time	^t stg	I _C =8A, I _{B1} =1.6A, I _{B2} =-3.2A, R _L =50Ω, V _{CC} =400V			3.0	μs
Fall Time	tf	I _C =8A, I _{B1} =1.6A, I _{B2} =-3.2A, R _L =50Ω, V _{CC} =400V			0.3	μs

Switching Time Test Circuit





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